PNP -1.5A -160V Middle Power Transistor

Parameter	Value
V_{CEO}	-160V
I _C	−1.5A

Features

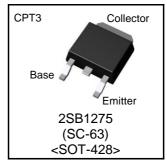
1) Suitable for Middle Power Driver

2) Complementary NPN Types: 2SD1918

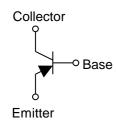
3) High voltage : $V_{CEO} = -160V$

4) Lead Free/RoHS Compliant.

Outline



•Inner circuit



Applications

Motor driver , LED driver Power supply

● Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SB1275	CPT3	6595	TL	330	16	2,500	B1275

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	-160	V
Collector-emitter voltage		V _{CEO}	-160	V
Emitter-base voltage		V_{EBO}	-5	V
Collector current	DC	I _C	-1.5	Α
	Pulsed	I _{CP} *1	-3.0	Α
Power dissipation		P _D *2	1	W
		P _D *3	10	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

^{*1} Pw=100ms, single pulse

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV_CEO	$I_C = -1 \text{mA}$	-160	-	-	V
Collector-base breakdown voltage	BV _{CBO}	$I_{C} = -50 \mu A$	-160	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = -50μA	– 5	ı	ı	V
Collector cut-off current	I _{CBO}	V _{CB} = -120V	ı	ı	-1	μΑ
Emitter cut-off current	I _{EBO}	$V_{EB} = -4V$	-	-	-1	μΑ
Collector-emitter saturation voltage	V _{CE(sat)} *4	$I_{C} = -1A, I_{B} = -0.1A$	ı	ı	-2	V
DC current gain	h _{FE}	$V_{CE} = -5V, I_{C} = -100 \text{mA}$	82	ı	180	1
Transition frequency	f _T	$V_{CE} = -5V, I_{E} = 100 \text{mA}$ f=30MH _Z	ı	50	-	MHz
Output capacitance	$C_{\sf ob}$	$V_{CB} = -10V, I_{E} = 0A,$ f = 1MHz	ı	30	-	pF

^{*4} Pulsed

●h_{FE} rank categories

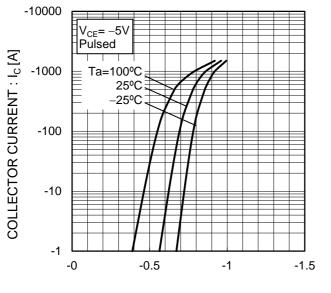
Rank	Р	
h _{FE}	82 to 180	

^{*2} Mounted on a substrate

^{*3} Tc=25°C

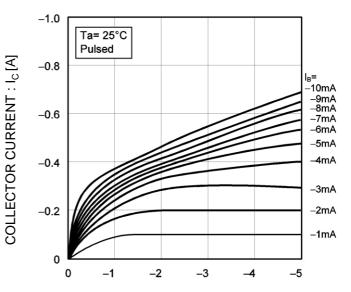
●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics



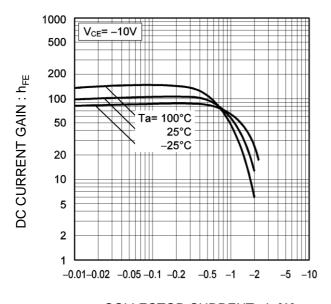
BASE TO EMITTER VOLTAGE : $V_{BE}[V]$

Fig.2 Typical Output Characteristics



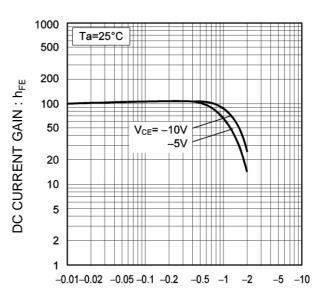
COLECTOR TO EMITTE VOLTAGE : $V_{CE}[V]$

Fig.3 DC Current Gain vs. Collector Current(I)



COLLECTOR CURRENT : I_C[A]

Fig.4 DC current gain vs. output current (II)



COLLECTOR CURRENT : I_C[A]

●Electrical characteristic curves(Ta = 25°C)

Fig.5 Collector-Emitter Saturation Voltage

vs. Collector Current (I) -10 $I_{C}/I_{B}=10$ -5 SATURATION VOLTAGE: V_{CE(sat)} [V] -2 -0.5COLLECTOR-EMITTER -0.2 -0.1 Ta= 100°C -0.0525°C -25°C -0.02-0.01-0.02 -0.05 -0.1 -0.2 -0.5

COLLECTOR CURRENT : I_C[A]

Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II) Ta=25°C -5 COLLECTOR-EMITTER SATURATION VOLTAGE : V_{CE(sat)} [V] -2 -0.5 -0.2 $I_{C}/I_{B}=50$ -0.120 -0.05-0.02 -0.01 -0.01-0.02 -0.05 -0.1 -0.2 -0.5 -5

COLLECTOR CURRENT : I_C[A]

Fig.7 Base-Emitter Saturation Voltage vs. Collector Current -10 $I_C/I_B=10$ -5 BASE-EMITTER SATURATION VOLTAGE : V_{BE(sat)} [V] -2 -1 -0.5Ta= -25°C 25°C 100°C -0.2 -0.01-0.02 -0.05 -0.1 -0.2 -5 -0.5

COLLECTOR CURRENT : I_C[A]

Fig.8 Gain Bandwidth Product vs. Emitter Current 1000 Ta= 25°C 500 V_{CE}= -5V TRANSITION FREQUENCY: fr [MHz] 200 100 50 20 10 5 2 20 50 100 200 500 1000 2 5 10 EMITTER CURRENT : I_E [mA]

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ROHM

●Electrical characteristic curves(Ta = 25°C)

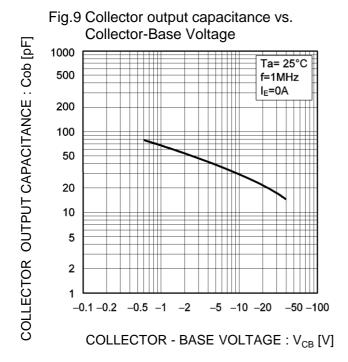
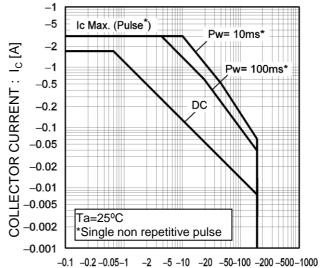
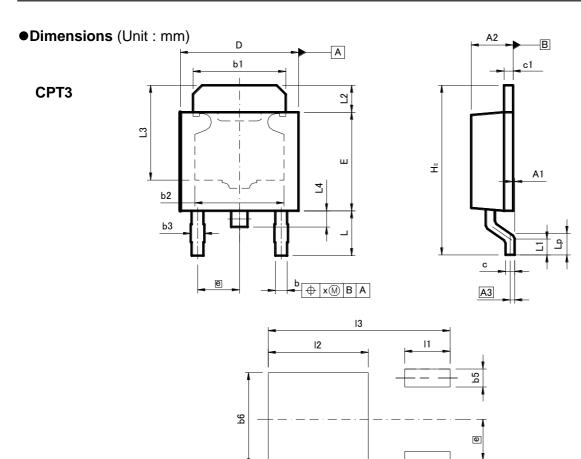


Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : $V_{CE}[V]$



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
A1	0.00	0.15	0.000	0.006	
A2	2.20	2.50	0.087	0.098	
A3	0.2	25	0.010		
b	0.55	0.75	0.022	0.030	
b1	5.00	5.30	0.197	0.209	
b2	5.0		0.1	97	
b3	0.	75	0.0	0.030	
С	0.40	0.60	0.016	0.024	
c1	0.40	0.60	0.016	0.024	
D	6.30	6.70	0.248	0.264	
E	5.40	5.80	0.213	0.228	
е	2.3	30	0.091		
HE	9.00	10.00	0.354	0.394	
L	2.20	2.80	0.087	0.110	
L1	0.80	1.40	0.031	0.055	
L2	1.20	1.80	0.047	0.071	
L3	5.30		0.209		
L4	0.90		0.035		
Lp	1.00	1.60	0.039	0.063	
Х	_	0.25	_	0.010	

DIM	MILIMI	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
b5	ı	1.00	ı	0.04	
b6	1	5.20	ı	0.205	
l1	-	2.50	-	0.098	
12	_	5.50	_	0.217	
13	-	10.00	_	0.394	

Dimension in mm / inches

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